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## DISCRETE SEMICONDUCTORS

# DATA SHEET

## BF510 to 513 N-channel silicon field-effect transistors

**Product specification** 

December 1997



## BF510 to 513

## **DESCRIPTION**

Asymmetrical N-channel planar epitaxial junction field-effect transistors in the miniature plastic envelope intended for applications up to the v.h.f. range in hybrid thick and thin-film circuits. Special features are the low feedback capacitance and the low noise figure. These features make the product very suitable for applications such as the r.f. stages in f.m. portables (BF510), car radios (BF511) and mains radios (BF512) or the mixer stage (BF513).

## **PINNING - SOT23**

1 = gate

2 = drain

3 = source

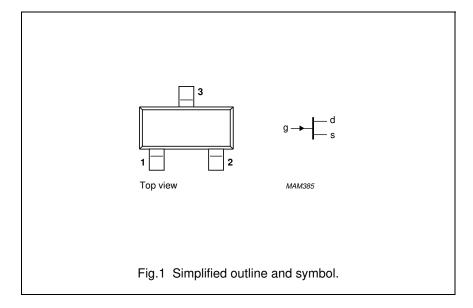
#### **MARKING CODE**

BF510 = S6p

BF511 = S7p

BF512 = S8p

BF513 = S9p



## **QUICK REFERENCE DATA**

Drain-source voltage	V <sub>DS</sub>	max.			20		V
Drain current (DC or average)	$I_D$	max.	30			mA	
Total power dissipation							
up to $T_{amb} = 40  ^{\circ}C$	$P_{tot}$	max.	250				mW
			BF510	511	512	513	
Drain current		> _	0.7	2.5	6	10	mA
$V_{DS} = 10 \text{ V}; V_{GS} = 0$	$I_{DSS}$	<	3.0	7.0	12	18	mA
Transfer admittance (common source)							
$V_{DS} = 10 \text{ V}; V_{GS} = 0; f = 1 \text{ kHz}$	$ y_{fs} $	>	2.5	4	6	7	mS
Feedback capacitance							
$V_{DS} = 10 \text{ V}; V_{GS} = 0$	$C_{rs}$	typ.	0.3	0.3	_	_	pF
$V_{DS} = 10 \text{ V}; I_D = 5 \text{ mA}$	$C_{rs}$	typ.	_	_	0.3	0.3	pF
Noise figure at optimum source admittance							
$G_S = 1 \text{ mS}; -B_S = 3 \text{ mS}; f = 100 \text{ MHz}$							
$V_{DS} = 10 \text{ V}; V_{GS} = 0$	F	typ.	1.5	1.5	_	_	dB
$V_{DS} = 10 \text{ V}; I_D = 5 \text{ mA}$	F	typ.	_	_	1.5	1.5	dB

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## **RATINGS**

Limiting values in accordance with the Absolute Maximum System (IEC 134)

Drain-source voltage	$V_{DS}$	max.	20	V
Drain-gate voltage (open source)	$V_{DGO}$	max.	20	V
Drain current (DC or average)	$I_D$	max.	30	mA
Gate current	$\pm I_{G}$	max.	10	mA
Total power dissipation up to T <sub>amb</sub> = 40 °C (note 1)	$P_{tot}$	max.	250	mW
Storage temperature range	$T_{stg}$	-65 to -	150	°C
Junction temperature	T <sub>i</sub>	max.	150	°C

## THERMAL RESISTANCE

From junction to ambient (note 1)

 $R_{th j-a} = 430 \text{ K/W}$ 

## Note

1. Mounted on a ceramic substrate of 8 mm  $\times$  10 mm  $\times$  0.7 mm.

## STATIC CHARACTERISTICS

 $T_{amb} = 25 \, ^{\circ}C$ 

			BF510	511	512	513	
Gate cut-off current							
$-V_{GS} = 0.2 \text{ V}; V_{DS} = 0$	$-I_{GSS}$	<	10	10	10	10	nΑ
Gate-drain breakdown voltage							
$I_S = 0; -I_D = 10 \mu A$	$-V_{(BR)GDO}$	>	20	20	20	20	V
Drain current V <sub>DS</sub> = 10 V; V <sub>GS</sub> = 0	I <sub>DSS</sub>	> <	0.7 3.0	2.5 7.0	6 12	10 18	mA mA
Gate-source cut-off voltage							
$I_D = 10 \ \mu A; \ V_{DS} = 10 \ V$	$-V_{(P)GS}$	typ.	0.8	1.5	2.2	3	V

BF510 to 513

## **DYNAMIC CHARACTERISTICS**

**Measuring conditions (common source):**  $V_{DS} = 10 \text{ V}; V_{GS} = 0; T_{amb} = 25 \text{ °C for BF510} \text{ and BF511}$ 

 $V_{DS} = 10 \text{ V}$ ;  $I_D = 5 \text{ mA}$ ;  $T_{amb} = 25 ^{\circ}\text{C}$  for BF512 and BF513

	* DS = 1	, i <sub>D</sub> – c	, in the ramb	- 20 0 10	. Di Oiz ai	ia bi o io	
y-parameters (common source)			BF510	511	512	513	
Input capacitance at f = 1 MHz	$C_{is}$	<	5	5	5	5	рF
Input conductance at f = 100 MHz	$g_{is}$	typ.	100	90	60	50	μS
Foodback capacitanes at f 1 MHz	$C_{rs}$	typ.	0.4	0.4	0.4	0.4	рF
Feedback capacitance at f = 1 MHz		<	0.5	0.5	0.5	0.5	рF
Transfer admittance at f = 1 kHz	$ y_{fs} $	>	2.5	4.0	4.0	3.5	mS
$V_{GS} = 0$ instead of $I_D = 5$ mA	$ y_{fs} $	>	_	_	6.0	7.0	mS
Transfer admittance at f = 100 MHz	$ y_{fs} $	typ.	3.5	5.5	5.0	5.0	mS
Output capacitance at f = 1 MHz	$C_{os}$	<	3	3	3	3	рF
Output conductance at f = 1 MHz	gos	<	60	80	100	120	μS
Output conductance at f = 100 MHz	$g_{os}$	typ.	35	55	70	90	μS
Noise figure at optimum source admittance							
$G_S = 1 \text{ mS}; -B_S = 3 \text{ mS};$							
f = 100 MHz	F	typ.	1.5	1.5	1.5	1.5	dB

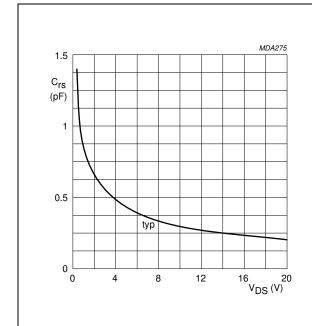
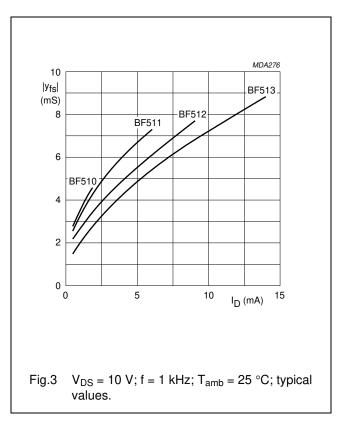
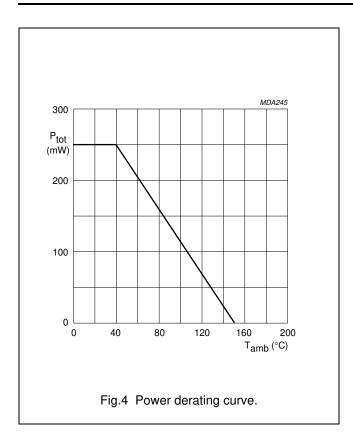


Fig.2  $V_{GS} = 0$  for BF510 and BF511;  $I_D = 5$  mA for BF512 and BF513; f = 1 MHz;  $T_{amb} = 25$  °C.



BF510 to 513

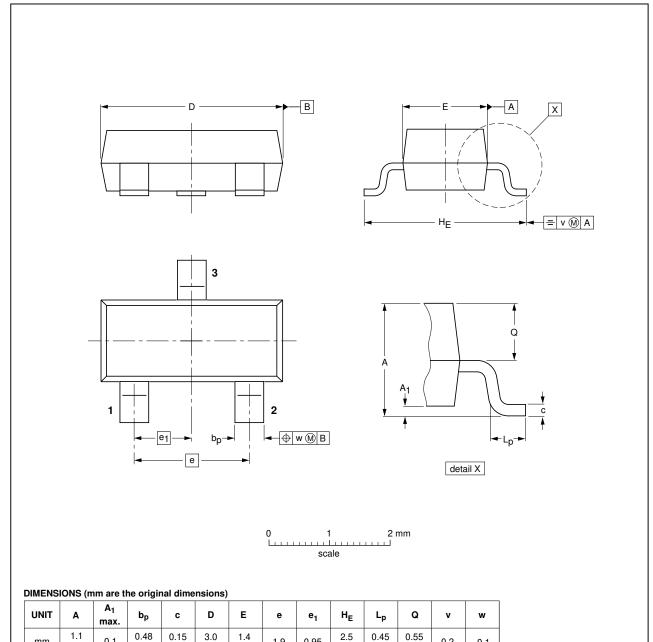


BF510 to 513

## **PACKAGE OUTLINE**

Plastic surface-mounted package; 3 leads

SOT23



OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT23		TO-236AB				<del>-04-11-04-</del> 06-03-16

0.95

1.9

0.1

0.2

0.1

0.38

0.9

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#### **DATA SHEET STATUS**

DOCUMENT STATUS(1)	PRODUCT STATUS <sup>(2)</sup>	DEFINITION
Objective data sheet	Development	This document contains data from the objective specification for product development.
Preliminary data sheet	Qualification	This document contains data from the preliminary specification.
Product data sheet	Production	This document contains the product specification.

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#### **Contact information**

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